NSN 5962-01-295-2918

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/psn/5062-01-205-2018

view Online at https://aerobasegroup.com/nsn/5962-01-295-2916
Body Length:
Between 1.380 inches and 1.420 inches
Body Width:
Between 0.560 inches and 0.600 inches
Body Height:
Between 0.080 inches and 0.140 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+155.0 degrees celsius
Features Provided:
High speed and bidirectional and high precision
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
First-in first-out
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Fiig:

A458a0

Demilitarization: Yes - demil/mli